



## True RMS-to-DC Converter

MX536A/MX636

### General Description

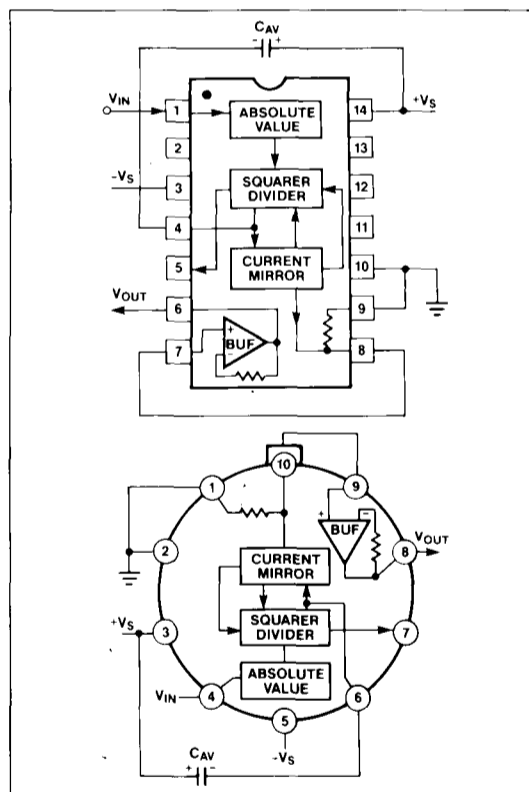
The MX536A and MX636 are true RMS-to-DC converters. They feature low power and are designed to accept low level input signals from 0 to  $7V_{rms}$  for the MX536A and 0 to  $200mV_{rms}$  for the MX636. Both devices accept complex input waveforms containing AC and DC components. They can be operated from either a single supply or dual supplies. Both devices draw less than 1mA of quiescent supply current making them ideal for battery powered applications.

Input and output offset, positive and negative waveform symmetry (DC reversal), and full-scale accuracy are laser trimmed, so that no external trims are required to achieve full rated accuracy.

### Applications

- Digital Multimeters
- Battery Powered Instruments
- Panel Meters
- Process Control

### Typical Operating Circuit



### Features

- ◆ True RMS-to-DC Conversion
- ◆ Computes RMS of AC and DC Signals
- ◆ Wide Response:
  - 2MHz Bandwidth for  $V_{rms} > 1V$  (MX536A)
  - 1MHz Bandwidth for  $V_{rms} > 100mV$  (MX636)
- ◆ Auxiliary dB Output: 60dB range for MX536A  
50dB range for MX636
- ◆ Single or Dual Supply Operation
- ◆ Low Power: 1.2mA typ for MX536A  
800 $\mu$ A typ for MX636

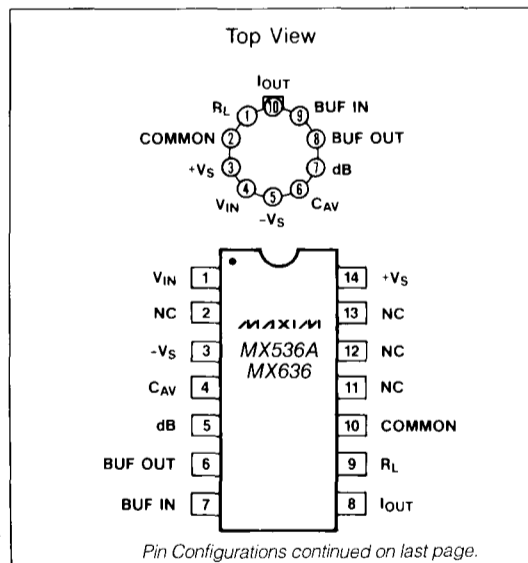
### Ordering Information

PART	TEMP. RANGE	PACKAGE*
MX536AJC/D	0°C to +70°C	Dice
MX536AJCWE	0°C to +70°C	16 Lead Wide S.O.
MX536AJD	0°C to +70°C	14 Lead Ceramic
MX536AJH	0°C to +70°C	10 Lead TO-100
MX536AJN	0°C to +70°C	14 Lead Plastic DIP
MX536AJQ*	0°C to +70°C	14 Lead CERDIP
MX536AKCWE	0°C to +70°C	16 Lead Wide S.O.
MX536AKD	0°C to +70°C	14 Lead Ceramic
MX536AKH	0°C to +70°C	10 Lead TO-100
MX536AKN	0°C to +70°C	14 Lead Plastic DIP

Ordering Information continued on last page.

\* Maxim reserves the right to ship Ceramic Packages in lieu of CERDIP Packages

### Pin Configurations



Pin Configurations continued on last page.



## True RMS-to-DC Converter

### ABSOLUTE MAXIMUM RATINGS

Supply Voltage: Dual Supplies (MX536A) ..... ±18V (MX636) ..... +12V	Power Dissipation (Package) (continued)
Single Supply (MX536A) ..... +36V (MX636) ..... +24V	Ceramic (Derate 10mW/°C above +75°C) ..... 500mW
Input Voltage (MX536A) ..... ±25V (MX636) ..... ±12V	TO-100 metal can (Derate 7mW/°C above +75°C) .. 450mW
Power Dissipation (Package)	Output Short Circuit Duration ..... Indefinite
Plastic DIP (Derate 12mW/°C above +75°C) ..... 450mW	Operating Temperature Range:
Small Outline (Derate 10mW/°C above +75°C) ... 400mW	Commercial (J,K) ..... 0°C to +70°C
	Military (S) ..... -55°C to +125°C
	Storage Temperature Range ..... -55°C to +150°C
	Lead Temperature (Soldering, 10 sec) ..... 300°C

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum ratings conditions for extended periods may affect the device reliability.

### ELECTRICAL CHARACTERISTICS—MX536A (T<sub>A</sub> = 25°C, +V<sub>S</sub> = +15V, -V<sub>S</sub> = -15V, unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
<b>TRANSFER EQUATION</b>		$V_{OUT} = [\text{avg}(V_{IN})^2]^{1/2}$			
<b>CONVERSION ACCURACY</b>					
Total Error, Internal Trim (Note 1)				+5 +0.5 +2 +0.2	mV + % of Reading
Total Error vs. Temperature	T <sub>MIN</sub> to +70°C			+0.1 +0.01 +0.05 +0.005 +0.1 +0.005	mV + % of Reading/°C
	+70°C to +125°C			+0.03 +0.005	
Total Error vs. Supply			+0.1 +0.01		mV + % of Reading/V
Total Error vs. DC Reversal			±0.2 +0.1		% of Reading
Total Error, External Trim (Note 1)			±3 ±0.3 ±2 ±0.1		mV + % of Reading
<b>ERROR vs. CREST FACTOR (Note 2)</b>					
Additional Error	Crest Factor 1 to 2 Crest Factor = 3 Crest Factor = 7		Specified Accuracy -0.1 -1.0		% of Reading
<b>FREQUENCY RESPONSE (Note 3)</b>					
Bandwidth for 1% Additional Error (0.09dB)	V <sub>IN</sub> = 10mV		5		kHz
	V <sub>IN</sub> = 100mV		45		
	V <sub>IN</sub> = 1V		120		
±3dB Bandwidth	V <sub>IN</sub> = 10mV		90		kHz
	V <sub>IN</sub> = 100mV		450		
	V <sub>IN</sub> = 1V		2.3		
<b>AVERAGING TIME CONSTANT (Fig. 3)</b>			25		ms/μF C <sub>AV</sub>
<b>INPUT CHARACTERISTICS</b>					
Input Signal Range	±15V Supplies Continuous rms Peak Transient		0 to 7		V <sub>rms</sub>
			+20		V <sub>PK</sub>
	±5V Supplies Continuous rms Peak Transient		0 to 2		V <sub>rms</sub>
		+7		V <sub>PK</sub>	
Safe Input	All Supplies		+25		V <sub>PK</sub>
Input Resistance		13.33	16.7	20.00	kΩ
Input Offset Voltage			0.8	+2	mV
			0.5	+1	

## True RMS-to-DC Converter

### ELECTRICAL CHARACTERISTICS—MX536A (Continued)

( $T_A = 25^\circ\text{C}$ ,  $+V_S = +15\text{V}$ ,  $-V_S = -15\text{V}$ , unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
<b>OUTPUT CHARACTERISTICS</b>						
Offset Voltage	$T_A = +25^\circ\text{C}$	MX536AJ MX536AK MX536AS	$\pm 1$ $\pm 0.5$	$\pm 2$ $\pm 1$ $\pm 2$	mV	
	$T_{\text{MIN}}$ to $T_{\text{MAX}}$	MX536AJ,AK MX536AS	$\pm 0.1$	$\pm 0.2$	mV/ $^\circ\text{C}$	
	Supply Voltage	MX536AJ,AK MX536AS	$\pm 0.1$ $\pm 0.2$		mV/V	
Output Voltage Swing	$\pm 15\text{V}$ Supplies $\pm 5\text{V}$ Supplies	0 to +11 0 to +2	+12.5		V	
Output Current	Source Sink	+5 -130			mA $\mu\text{A}$	
Short Circuit Current			20		mA	
Output Resistance				0.5	$\Omega$	
<b>dB OUTPUT</b>						
Error	$V_{\text{IN}} = 7\text{mV}$ to $7V_{\text{rms}}$ , $0\text{dB} = 1V_{\text{rms}}$	MX536AJ MX536AK MX536AS	$\pm 0.4$ $\pm 0.2$ $\pm 0.5$	$\pm 0.6$ $\pm 0.3$ $\pm 0.6$	dB	
Scale Factor			-3		mV/dB	
Scale Factor TC (Uncompensated)			+0.33		% of Reading/ $^\circ\text{C}$	
$I_{\text{REF}}$	$0\text{dB} = 1V_{\text{rms}}$		5	20	80	$\mu\text{A}$
$I_{\text{REF}}$ Range			1		100	$\mu\text{A}$
<b><math>I_{\text{OUT}}</math> TERMINAL</b>						
$I_{\text{OUT}}$ Scale Factor			40		$\mu\text{A}/V_{\text{rms}}$	
$I_{\text{OUT}}$ Scale Factor Tolerance			$\pm 10$	+20		%
Output Resistance		20	25	30		k $\Omega$
Voltage Compliance			$-V_S$ to ( $+V_S - 2.5\text{V}$ )			V
<b>BUFFER AMPLIFIER</b>						
Input and Output Voltage Range			$-V_S$ to ( $+V_S - 2.5\text{V}$ )			V
Input Offset Voltage	$R_S = 25\text{k}\Omega$		$\pm 0.5$	$\pm 4$		mV
Input Bias Current			20	300		nA
Input Resistance			$10^8$			$\Omega$
Output Current	Source Sink		+5 -130			mA $\mu\text{A}$
Short Circuit Current			20			mA
Small Signal Bandwidth			1			MHz
Slew Rate (Note 4)			5			V/ $\mu\text{s}$

**Note 1:** Accuracy is specified for 0 to  $7V_{\text{rms}}$ , DC or 1kHz sinewave input with the MX536A connected as in Figure 2.

**Note 2:** Error vs. crest factor is specified as an additional error for  $1V_{\text{rms}}$  rectangular pulse stream, pulse width =  $200\mu\text{s}$ .

**Note 3:** Input voltages are expressed in volts rms, and error as % of reading.

**Note 4:** With  $2\text{k}\Omega$  external pulldown resistor.

## True RMS-to-DC Converter

MX536A/MX636

### ELECTRICAL CHARACTERISTICS—MX636

(T<sub>A</sub> = 25°C, +V<sub>S</sub> = +3V, -V<sub>S</sub> = -5V, unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
<b>TRANSFER EQUATION</b>		$V_{OUT} = [\text{avg.}(V_{IN})^2]^{1/2}$			
<b>CONVERSION ACCURACY</b>					
Total Error, Internal Trim (Notes 5, 6)		MX636J MX636K		±0.5 ±0.6 ±0.2 ±0.5	mV ±% of Reading
Total Error vs. Temperature (0°C to +70°C)		MX636J MX636K		±0.1 ±0.01 ±0.1 ±0.005	mV ±% of Reading/°C
Total Error vs. Supply			±0.1 ±0.01		mV ±% of Reading/V
Total Error vs. DC Reversal	V <sub>IN</sub> = 200mV	MX636J MX636K		±0.2 ±0.1	±% of Reading
Total Error, External Trim (Note 5)		MX636J MX636K		±0.3 ±0.1 ±0.1 ±0.1	mV ±% of Reading
<b>ERROR vs. CREST FACTOR (Note 3)</b>					
	Crest Factor 1 to 2 Crest Factor = 3 Crest Factor = 6		Specified Accuracy -0.2 -0.5		±% of Reading
<b>FREQUENCY RESPONSE (Notes 6, 8)</b>					
Bandwidth for 1% Additional Error (0.09dB)	V <sub>IN</sub> = 10mV V <sub>IN</sub> = 100mV V <sub>IN</sub> = 200mV		14 90 130		kHz
±3dB Bandwidth	V <sub>IN</sub> = 10mV V <sub>IN</sub> = 100mV		100 900		kHz
	V <sub>IN</sub> = 200mV		1.5		MHz
<b>AVERAGING TIME CONSTANT (Fig. 3)</b>			25		ms/μF C <sub>AV</sub>
<b>INPUT CHARACTERISTICS</b>					
Input Signal Range	Continuous rms, All Supplies		0 to 200		mV <sub>rms</sub>
	Peak Transient +3V, -5V Supplies ±2.5V Supplies ±5V Supplies			±2.8 ±2 ±5	V <sub>PK</sub>
	Safe Input	All Supplies		±12	V <sub>PK</sub>
Input Resistance		5.33	6.7	8.00	kΩ
Input Offset Voltage		MX636J		±0.5	mV
		MX636K		±0.2	mV

## True RMS-to-DC Converter

**MX536A/MX636**

### ELECTRICAL CHARACTERISTICS—MX636 (Continued)

( $T_A = 25^\circ\text{C}$ ,  $+V_S = +3\text{V}$ ,  $-V_S = -5\text{V}$ , unless otherwise noted.)

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
<b>OUTPUT CHARACTERISTICS</b> (Note 5)						
Offset Voltage	$T_A = +25^\circ\text{C}$	MX636J MX636K			+0.5 $\pm 0.2$	mV
	$T_{\text{MIN}}$ to $T_{\text{MAX}}$			+10		$\mu\text{V}/^\circ\text{C}$
	With Supply Voltage			$\pm 0.1$		mV/V
Output Voltage Swing	+3V, -5V Supplies		0 to 1			V
	$\pm 5\text{V}$ to $\pm 16.5\text{V}$ Supplies		0 to 1	+1.4		
Output Resistance			8	10	12	k $\Omega$
<b>dB OUTPUT</b>						
Error	$7\text{mV} \leq V_{\text{IN}} \leq 300\text{mV}$	MX636J MX636K		$\pm 0.3$ $\pm 0.1$	+0.5 $\pm 0.2$	dB
Scale Factor				-3		mV/dB
Scale Factor Tempco				+0.33 -0.033		$\% / ^\circ\text{C}$ dB/ $^\circ\text{C}$
$I_{\text{REF}}$	0dB = $1V_{\text{rms}}$		2	4	8	$\mu\text{A}$
$I_{\text{REF}}$ Range			1		50	$\mu\text{A}$
<b><math>I_{\text{OUT}}</math> TERMINAL</b>						
$I_{\text{OUT}}$ Scale Factor				100		$\mu\text{A}/V_{\text{rms}}$
$I_{\text{OUT}}$ Scale Factor Tolerance			-20	$\pm 10$	+20	%
Output Resistance			8	10	12	k $\Omega$
Voltage Compliance				$-V_S$ to ( $+V_S - 2.0\text{V}$ )		V
<b>BUFFER AMPLIFIER</b>						
Input and Output Voltage Range				$-V_S$ to ( $+V_S - 2\text{V}$ )		V
Input Offset Voltage	$R_S = 10\text{k}\Omega$	MX636J MX636K		+0.8 $\pm 0.5$	+2 $\pm 1$	mV
Input Current				20	60	nA
Input Resistance				$10^8$		$\Omega$
Output Current	Source Sink			+5 -130		$\mu\text{A}$ mA
Short Circuit Current				20		mA
Small Signal Bandwidth				1		MHz
Slew Rate (Note 9)				5		V/ $\mu\text{s}$
<b>POWER SUPPLY</b>						
Rated Performance				+2/-2.5	+3/-5	V
Dual Supplies				+5	+16.5	
Single Supply					+24	
Quiescent Current (Note 10)				0.8	1	mA

**Note 5:** Accuracy is specified for 0 to 200mV, DC or 1kHz sinewave input. Accuracy is degraded at higher rms signal levels.

**Note 6:** Measured at pin 8 of DIP and S.O. ( $I_{\text{OUT}}$ ), with pin 9 tied to COMMON.

**Note 7:** Error vs. crest factor is specified as an additional error for 200mV<sub>rms</sub> rectangular pulse input, pulse width = 200 $\mu\text{s}$ .

**Note 8:** Input voltages are expressed in volts rms.

**Note 9:** With 10k $\Omega$  external pulldown resistor from pin 6 (BUF OUT) to  $-V_S$ .

**Note 10:** With BUF input tied to COMMON.

**MAXIM**

## True RMS-to-DC Converter

### Detailed Description

The MX536A/636 uses an implicit method of RMS computation that overcomes the dynamic range as well as other limitations inherent in a straightforward computation of the RMS. The actual computation performed by the MX536A/636 follows the equation:

$$V_{rms} = \text{Avg.} [V_{IN}^2 / V_{rms}]$$

The input voltage,  $V_{IN}$ , applied to the MX536A/636 is processed by an absolute value/voltage to current converter that produces a unipolar current  $I_1$  (see Figure 1). This current drives one input of a squarer/divider that produces a current  $I_4$  that has a transfer function:

$$I_4 = \frac{I_1^2}{I_3}$$

The current  $I_4$  drives the internal current mirror through a low pass filter formed by  $R_1$  and an external capacitor,  $C_{AV}$ . As long as the time constant of this filter is greater than the longest period of the input signal,  $I_4$  is averaged. The current mirror returns a current,  $I_3$ , to the square/divider to complete the circuit. The current  $I_4$  is then a function of the average of  $(I_1^2/I_4)$  which is equal to  $I_{1,rms}$ .

The current mirror also produces a  $2 \cdot I_4$  output current,  $I_{OUT}$ , that can be used directly or converted to a voltage using resistor  $R_2$  and the internal buffer to provide a low impedance voltage output. The transfer function for the MX536A/636 is:

$$V_{OUT} = 2 \cdot R_2 \cdot I_{rms} = V_{IN}$$

The dB output is obtained by the voltage at the emitter of Q3 which is proportional to the  $-\log V_{IN}$ . The emitter follower Q5 buffers and level shifts this voltage so that the dB output is zero when the externally set emitter current for Q5 approximates  $I_3$ .

### Standard Connection (Figure 2)

The standard rms connection requires only one external component,  $C_{AV}$ . In this configuration the MX536A/636 measures the rms of the AC and DC levels present at the input, but shows an error for low frequency inputs as a function of the  $C_{AV}$  filter capacitor. Figure 3 gives practical values of  $C_{AV}$  for various values of averaging error over frequency for the standard rms connections (no post filtering). If a  $3\mu F$  capacitor is chosen, the additional error at 100Hz will be 1%. If the DC error can be rejected, a capacitor should be connected in series with the input, as would typically be the case in single supply operation.

The input and output signal ranges are a function of the supply voltages. Refer to the electrical characteristics for guaranteed performance. The buffer amplifier can be used either for lowering the output impedance of the circuit, or for other applications such as buffering high impedance input signals. The MX536A/636 can be used in current output mode by disconnecting the internal load resistor  $R_L$  from ground. The current output is available at pin 8 (pin 10 on the "H" package) with a nominal scale of  $40\mu A/\text{Volt rms input}$  for the MX536A and  $100\mu A/\text{Volt rms input}$  for the MX636. The output is positive.

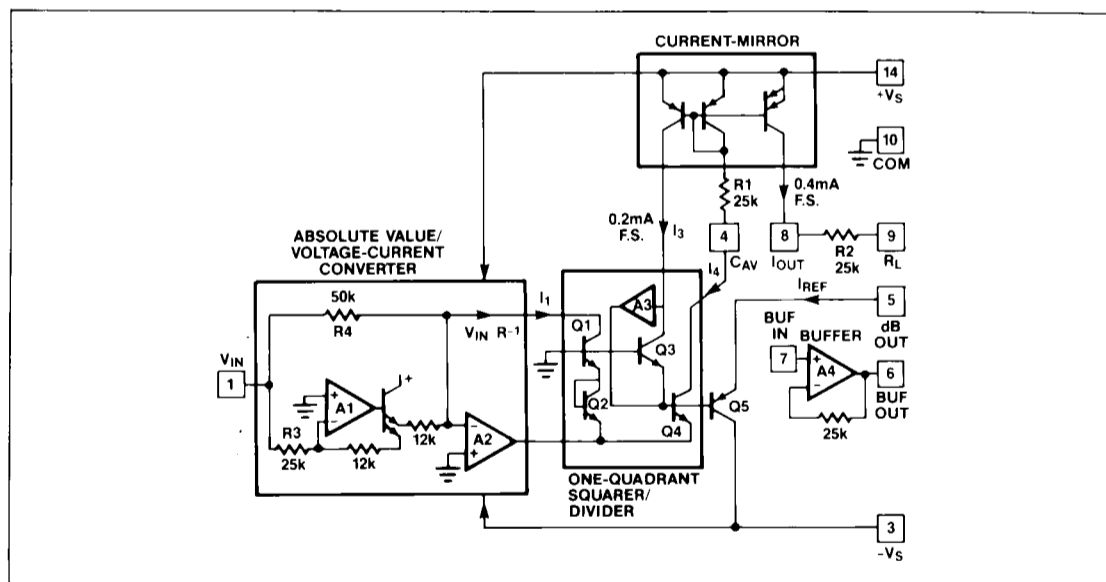


Figure 1. MX536A Simplified Schematic

## True RMS-to-DC Converter

### High Accuracy Adjustments

The accuracy of the MX536A/636 can be improved by the addition of external trims as shown in Figure 4. R4 trims the offset. The input should be grounded and R4 adjusted to give zero volts output from pin 6. R1 is trimmed to give the correct value for either a calibrated DC input or a calibrated AC signal. For example: 200mV DC input should give 200mV DC output, a  $\pm 200\text{mV}$  peak to peak sine wave should give 141mV DC output.

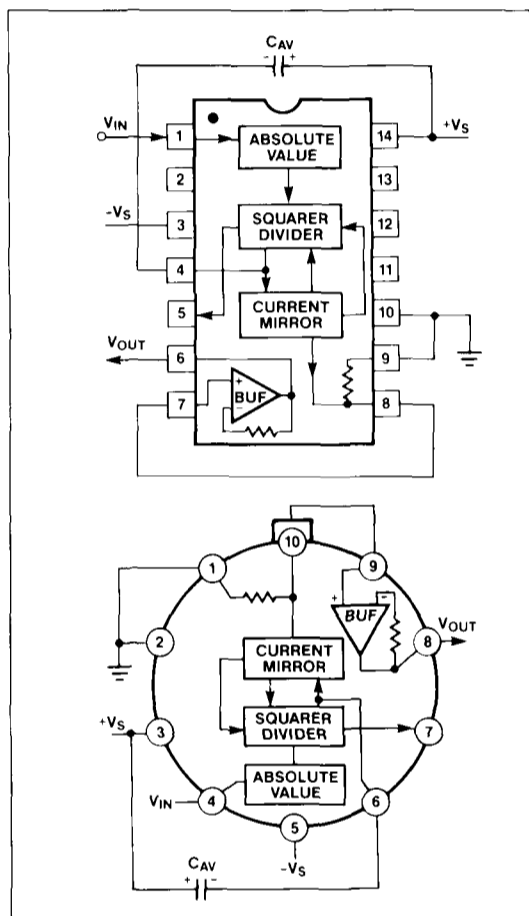


Figure 2. MX536A/MX636 Standard rms Connection

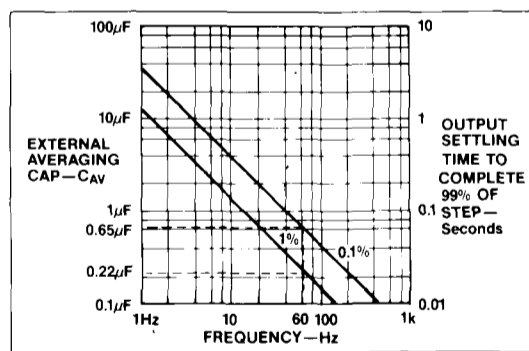


Figure 3. Lower Frequency for Stated % of Reading Error and Settling Time for Circuit Shown in Figure 2

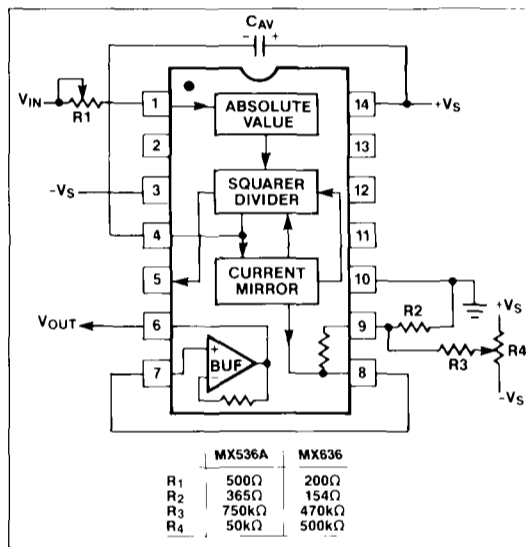


Figure 4. Optional External Gain and Output Offset Trims

### Single Supply Operation

Both the MX536A and MX636 can be used with single supplies down to +5V. See Figure 5. The major limitation of this connection is that only AC signals can be measured since the differential input stage must be biased off ground for proper operation. The load resistor is necessary to provide output sink current. The input signal is coupled through C2 and the value chosen so that the desired low frequency break point is obtained with the input resistance of 16.7k ohms for the MX536A and 6.7k ohms for the MX636.

Figure 5 shows how to bias pin 10 within the range of the supply voltage (pin 2 on "H" packages). It is critical that no extraneous signals are coupled into this pin. A capacitor connected between pin 10 and ground is recommended. The common pin requires less than 5µA of input current, and if the current flowing through the resistors R1 and R2 is chosen to be approximately 10 times the common pin current, or 50µA, the resistor values can easily be calculated.

## True RMS-to-DC Converter

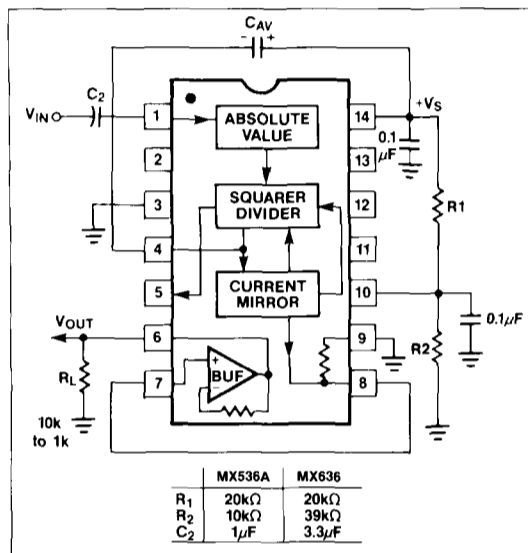


Figure 5. Single Supply Operation

### Choosing the Averaging Time Constant

Both the MX536A and MX636 compute the rms value of AC and DC signals. At low frequencies and DC, the output tracks the input exactly; at higher frequencies, the average output approaches the rms value of the input signal. The actual output differs from the ideal by an average (or DC) error plus some amount of ripple.

The DC error term is a function of the value of  $C_{AV}$  and the input signal frequency. The output ripple is inversely proportional to the value of  $C_{AV}$ . Waveforms with high crest factors, such as a pulse train with low duty cycle, should have an average time constant chosen to be at least ten times the signal period.

Using a large value of  $C_{AV}$  to remove the output ripple increases the settling time for a step change in the input signal level. Figure 3 shows the relationship between  $C_{AV}$  and settling time, where 115ms settling equals 1μF of  $C_{AV}$ . The settling time, or time for the rms converter to settle to within a given percent of the change in rms level, is set by the averaging time constant, which varies approximately 2:1 between increasing and decreasing input signals. For example, increasing input signals require 2.3 time constants to settle to within 1% and 4.6 time constants for decreasing signals levels.

In addition, the settling time also varies with input signal levels, increasing as the input signal is reduced, and decreasing as the input is increased as shown in figures 6(a) and 6(b).

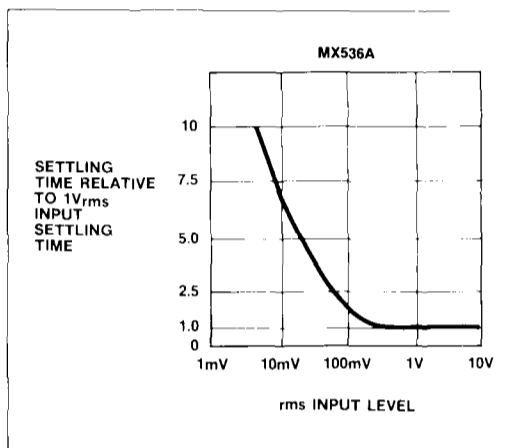


Figure 6A. MX536A Settling Time vs. Input Level

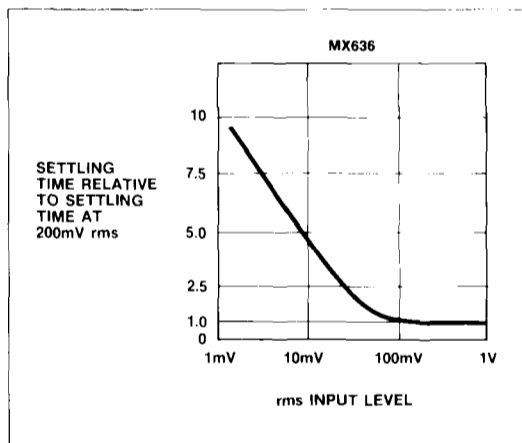


Figure 6B. MX636 Settling Time vs. Input Level



## True RMS-to-DC Converter

MX536A/MX636

### Using Post Filters

A post filter allows a smaller value of  $C_{AV}$ , and reduces ripple and improves the overall settling time. The value of  $C_{AV}$  should be just large enough to give the maximum DC error at the lowest frequency of interest. The post filter is used to remove excess output ripple. Figures 7, 8 and 9 give recommended filter connections and values for both the MX536A and MX636. Table 1 lists the number of time constants required for the rms section to settle to within different percentages of the final value for a step change in the input signal.

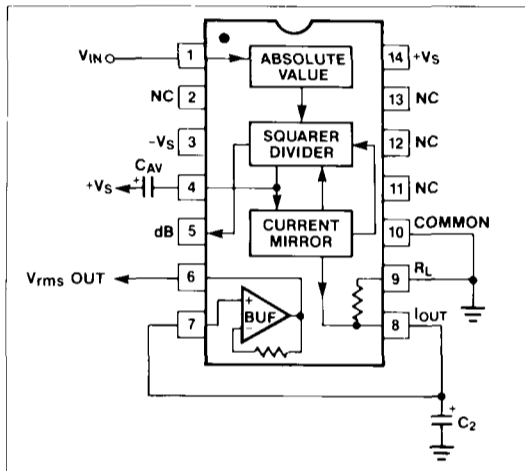


Figure 7. MX536A/MX636 with a 1 Pole Output Filter

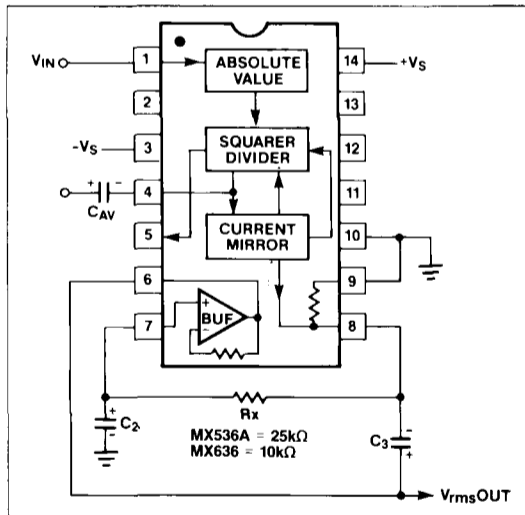


Figure 8. MX536A/MX636 with a 2 Pole Output Filter

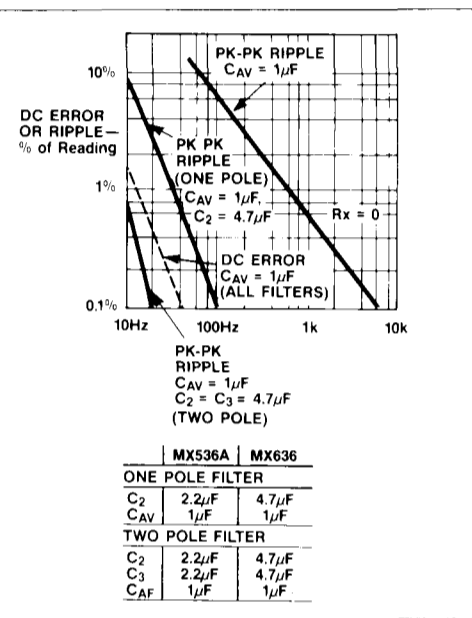


Figure 9. Performance Features of Various Filter Types for MX536A/MX636

Table 1. Number of RC Time Constants ( $\tau$ ) Required for MX536A, MX636, rms Converters to Settle to Within Stated % of Final Value

Basic Formulas	For Increasing Amplitudes	For Decreasing Amplitudes
	$\Delta V \sqrt{1 - e^{-T/RC}}$	$\Delta V \sqrt{e^{-T/RC}}$
Settling Time to Within Stated % of New rms Level		
1%	2.0 $\tau$ (4.6 $\tau$ )	4.6 $\tau$ (4.6 $\tau$ )
0.1%	3.1 $\tau$ (6.9 $\tau$ )	6.9 $\tau$ (6.9 $\tau$ )
0.01%	4.2 $\tau$ (9.2 $\tau$ )	9.2 $\tau$ (9.2 $\tau$ )
( $\tau$ ) Settling Times for Linear RC Filter		

## True RMS-to-DC Converter

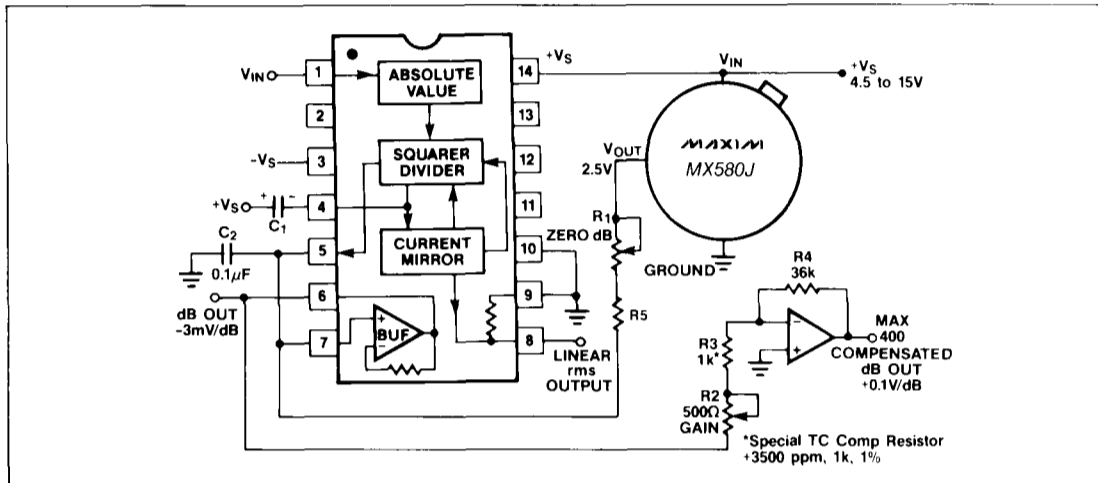


Figure 10. dB Connection

### The Decibel (dB) Output

The dB output of the MX536A/636 originates in the squarer/divider section and works well over a 60dB range. The connection for dB measurements is shown in Figure 10. The dB output has a temperature drift of 0.03dB/°C and in some applications may need to be compensated. Figure 10 shows a compensation scheme. The amplifier can be used to scale the output for a particular application. The values used in Figure 10 give an output of +100mV/dB.

### Frequency Response

The MX536A/636 utilizes a logarithmic circuit in performing the rms computation of the input signal. The bandwidth of the rms converters are proportional to signal level. Figures 11 and 12 represent the frequency response of the converters from 10mV to 7V<sub>rms</sub> for the MX536A and 1mV to 1V for the MX636 respectively. The dashed lines indicate the upper frequency limits for 1%, 10%, and ±3dB of reading additional error. Caution must be used when designing rms measuring systems so that overload does not occur. The input clipping level for the MX636 is ±12V, and for the MX536A it is ±20V. A 7V<sub>rms</sub> signal with a crest factor of 3 has a peak input of 21 volts!

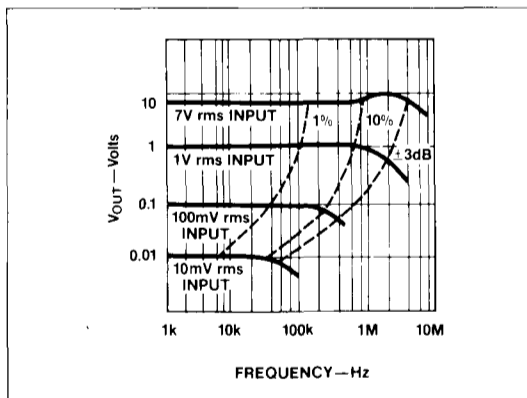


Figure 11. MX536A High Frequency Response

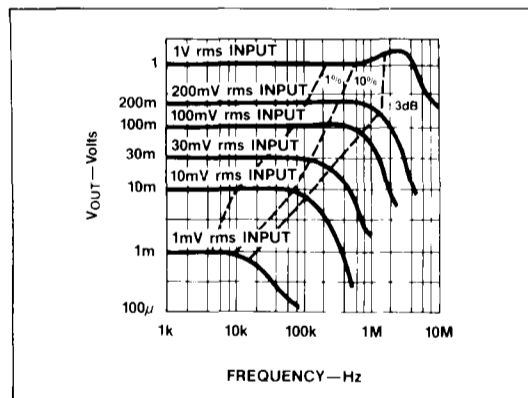
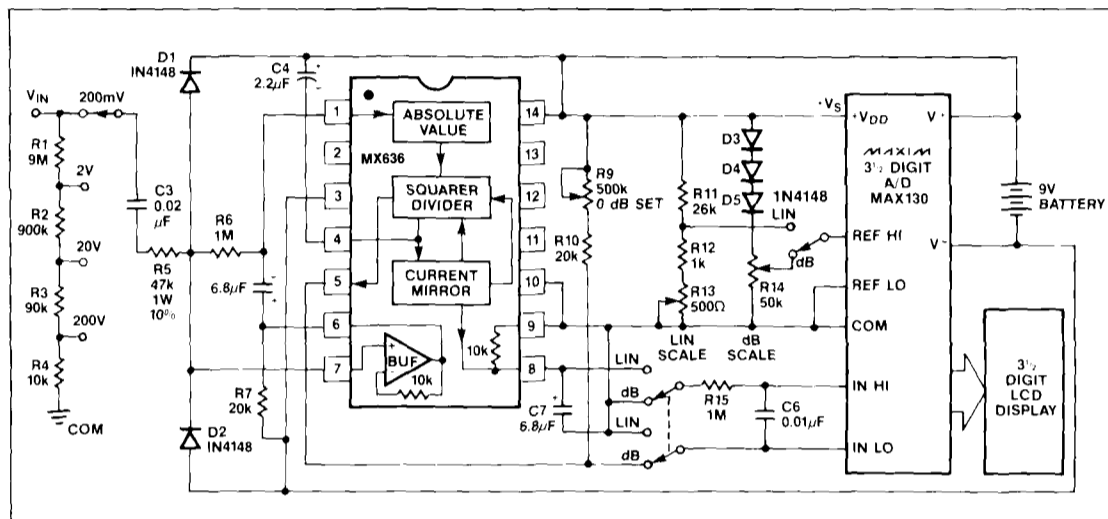


Figure 12. MX636 High Frequency Response

## True RMS-to-DC Converter



MX536A/MX636

Figure 13. A Portable, High Z Input, rms DPM and dB Meter

### Application in a low cost DVM

A low cost digital voltmeter (DVM) using just two integrated circuits plus supporting circuitry and LCD display is shown in Figure 13. The MAX130 is a 3½ digit integrating A/D converter with precision band-gap reference. The 10Mohm input attenuator is AC coupled to pin 6 of the MX636 buffer amplifier. The output from the MX636 is connected to the MAX130 to give a direct reading to the LCD display.

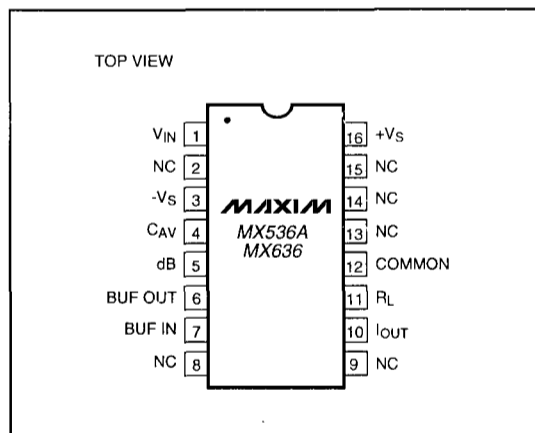
## True RMS-to-DC Converter

### Ordering Information (continued)

PART	TEMP. RANGE	PACKAGE*
MX536AKQ*	0°C to +70°C	14 Lead CERDIP
MX536ASD	-55°C to +125°C	14 Lead Ceramic
MX536ASH	-55°C to +125°C	10 Lead TO-100
MX536ASQ*	-55°C to +125°C	14 Lead CERDIP
MX636JC/D	0°C to +70°C	Dice
MX636JCWE	0°C to +70°C	16 Lead Wide S.O.
MX636JD	0°C to +70°C	14 Lead Ceramic
MX636JH	0°C to +70°C	10 Lead TO-100
MX636JN	0°C to +70°C	14 Lead Plastic DIP
MX636JQ*	0°C to +70°C	14 Lead CERDIP
MX636KCWE	0°C to +70°C	16 Lead Wide S.O.
MX636KD	0°C to +70°C	14 Lead Ceramic
MX636KH	0°C to +70°C	10 Lead TO-100
MX636KN	0°C to +70°C	14 Lead Plastic DIP
MX636KQ*	0°C to +70°C	14 Lead CERDIP

\* Maxim reserves the right to ship Ceramic Packages in lieu of CERDIP Packages

### Pin Configuration (continued)



Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

12 **Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 (408) 737-7600**

© 1994 Maxim Integrated Products Printed USA **MAXIM** is a registered trademark of Maxim Integrated Products.